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74LV574

Octal D-type flip-flop; positive edge-trigger; 3-state Rev. 04 — 14 May 2009 Produc

Product data sheet

General description 1.

The 74LV574 is an octal D-type flip-flop featuring separate D-type inputs for each flip-flop and non-inverting 3-state outputs for bus oriented applications. A clock (CP) and an output enable (OE) input are common to all flip-flops. It is a low-voltage Si-gate CMOS device and is pin and functionally compatible with the 74HC574 and 74HCT574.

The eight flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW to HIGH CP transition.

When \overline{OE} is LOW, the contents of the eight flip-flops is available at the outputs. When \overline{OE} is HIGH, the outputs go to the high-impedance OFF-state. Operation of the OE input does not affect the state of the flip-flops.

2. **Features**

- Wide operating voltage: 1.0 V to 5.5 V
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between $V_{CC} = 2.7 \text{ V}$ and $V_{CC} = 3.6 \text{ V}$
- Typical output ground bounce < 0.8 V at V_{CC} = 3.3 V and T_{amb} = 25 °C
- Typical HIGH-level output voltage (V_{OH}) undershoot: > 2 V at V_{CC} = 3.3 V and $T_{amb} = 25 \, ^{\circ}C$
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Common 3-state output enable input
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

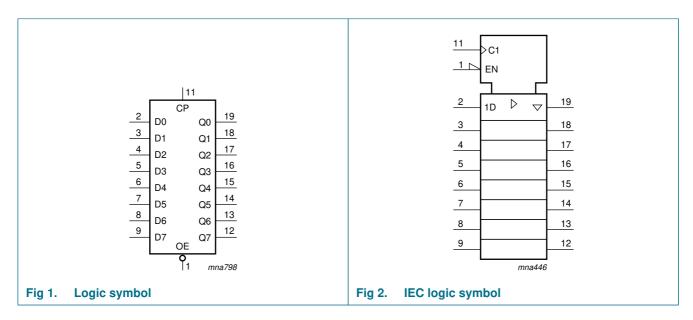
Table 1. **Ordering information**

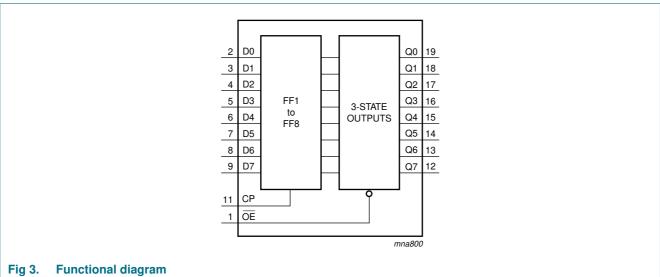
Туре	Package										
number	Temperature range	Name	Description	Version							
74LV574N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1							
74LV574D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1							
74LV574DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1							
74LV574PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1							



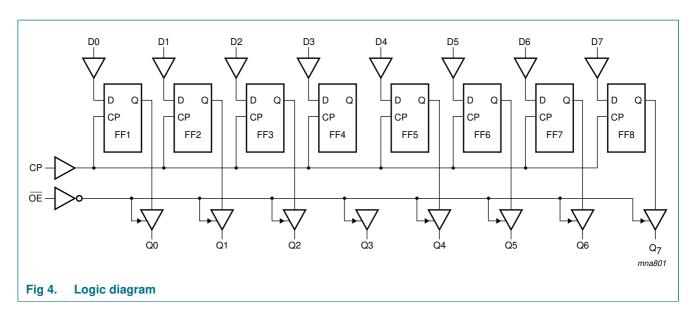
Octal D-type flip-flop; positive edge-trigger; 3-state

4. Functional diagram



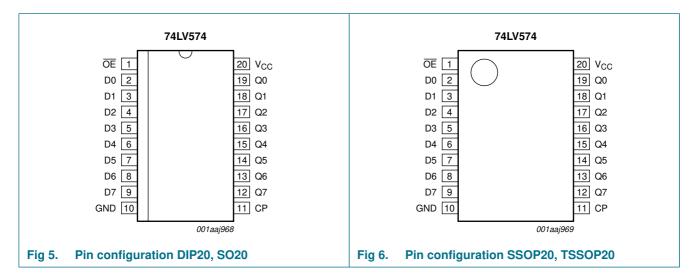


Octal D-type flip-flop; positive edge-trigger; 3-state



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
ŌĒ	1	output enable input (active LOW)
D0 to D7	2, 3, 4, 5, 6, 7, 8, 9	data input
GND	10	ground (0 V)
CP	11	clock input (LOW to HIGH; edge triggered)
Q0 to Q7	19, 18, 17, 16, 15, 14, 13, 12	data output
V _{CC}	20	supply voltage

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Octal D-type flip-flop; positive edge-trigger; 3-state

6. Functional description

Table 3. Function table^[1]

Operating mode	Input		Internal flip-flop	Output	
	ŌĒ	CP Dn			Qn
Load and read register	L	\uparrow	I	L	L
	L	\uparrow	h	Н	Н
Load register and disable	Н	\uparrow	I	L	Z
outputs	Н	↑	h	Н	Z

^[1] H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the LOW to HIGH CP transition

L = LOW voltage level

I = LOW voltage level one set-up time prior to the LOW to HIGH CP transition

Z = high-impedance OFF-state

↑ = LOW to HIGH clock transition

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±50	mA
Io	output current	$V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2]		
		DIP20	-	750	mW
		SO20, SSOP20 and TSSOP20	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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^[2] For DIP20 packages: above 70 °C the value of P_{tot} derates linearly with 12 mW/K. For SO20 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K. For (T)SSOP20 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

Octal D-type flip-flop; positive edge-trigger; 3-state

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage[1]		1.0	3.3	5.5	V
V_{I}	input voltage		0	-	V_{CC}	V
V _O	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$	-	-	500	ns/V
		$V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$	-	-	200	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	100	ns/V
		$V_{CC} = 3.6 \text{ V to } 5.5 \text{ V}$	-	-	50	ns/V

^[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to V_{CC} = 5.5 V, but LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	35 °C	–40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		$V_{CC} = 2.0 \text{ V}$	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7V _{CC}	-	-	0.7V _{CC}	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
		V _{CC} = 2.0 V	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_O = -100 \ \mu A; \ V_{CC} = 1.2 \ V$	-	1.2	-	-	-	V
		$I_{O} = -100 \ \mu A; \ V_{CC} = 2.0 \ V$	1.8	2.0	-	1.8	-	V
		$I_{O} = -100 \ \mu A; \ V_{CC} = 2.7 \ V$	2.5	2.7	-	2.5	-	V
		$I_O = -100 \ \mu A; \ V_{CC} = 3.0 \ V$	2.8	3.0	-	2.8	-	V
		$I_O = -100 \ \mu A; \ V_{CC} = 4.5 \ V$	4.3	4.5	-	4.3	-	V
		$I_O = -8 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.82	-	2.2	-	٧
		$I_{O} = -16 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.6	4.2	-	3.5	-	V

Octal D-type flip-flop; positive edge-trigger; 3-state

 Table 6.
 Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
V _{OL} LOW-level output voltage		$V_I = V_{IH}$ or V_{IL}				'		
		$I_O = 100 \mu A; V_{CC} = 1.2 V$	-	0	-	-	-	V
		$I_O = 100 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.2	-	0.2	V
		$I_O = 100 \ \mu A; \ V_{CC} = 2.7 \ V$	-	0	0.2	-	0.2	V
		$I_O = 100 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.2	-	0.2	V
		$I_O = 100 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.2	-	0.2	V
		$I_O = 8 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.25	0.40	-	0.50	V
		$I_{O} = 16 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.35	0.55	-	0.65	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	1.0	μΑ
l _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-	-	5	-	10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20	-	160	μΑ
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μΑ
C _I	input capacitance		-	3.5	-	-	-	рF

^[1] Typical values are measured at T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd} propagation delay		CP to Qn; see Figure 7	[2]						
		V _{CC} = 1.2 V		-	80	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		-	27	34	-	43	ns
		V _{CC} = 2.7 V		-	20	25	-	31	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	13	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	15	20	-	25	ns
		V _{CC} = 4.5 V to 5.5 V		-	-	17	-	21	ns
t _{en}	enable time	OE to Qn; see Figure 8	[4]						
		V _{CC} = 1.2 V		-	70	-	-	-	ns
		V _{CC} = 2.0 V		-	24	34	-	43	ns
		V _{CC} = 2.7 V		-	18	25	-	31	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	13	20	-	25	ns
		V _{CC} = 4.5 V to 5.5 V		-	-	17	-	21	ns

Octal D-type flip-flop; positive edge-trigger; 3-state

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

Symbol	Parameter	Conditions		-40	°C to +85	°C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	1
t _{dis}	disable time	OE to Qn; Figure 8	<u>[5]</u>		'				
		V _{CC} = 1.2 V		-	75	-	-	-	ns
		V _{CC} = 2.0 V		-	27	27	-	34	ns
		V _{CC} = 2.7 V		-	21	21	-	26	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	16	17	-	21	ns
		V _{CC} = 4.5 V to 5.5 V	[3]	-	-	15	-	18	ns
t _W	pulse width	CP, HIGH or LOW; see Figure 7							
		V _{CC} = 2.0 V		34	9	-	41	-	ns
		$V_{CC} = 2.7 \text{ V}$		25	6	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	20	5	-	24	-	ns
t _{su}	set-up time	Dn to CP; see Figure 9							
		V _{CC} = 1.2 V		-	10	-	-	-	ns
		V _{CC} = 2.0 V		22	4	-	26	-	ns
		V _{CC} = 2.7 V		16	3	-	19	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	13	2	-	15	-	ns
t _h	hold time	Dn to CP; see Figure 9							
		V _{CC} = 1.2 V		-	-10	-	-	-	ns
		V _{CC} = 2.0 V		5	-4	-	5	-	ns
		V _{CC} = 2.7 V		5	-3	-	5	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	5	-2	-	5	-	ns
f _{max}	maximum	see Figure 7							
	frequency	$V_{CC} = 2.0 \text{ V}$		15	40	-	12	-	MHz
		$V_{CC} = 2.7 \text{ V}$		19	58	-	16	-	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	24	70	-	20	-	MHz
C_{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	[6]		25				pF

^[1] Typical values are measured at $T_{amb} = 25$ °C.

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

^[3] Typical value measured at $V_{CC} = 3.3 \text{ V}$.

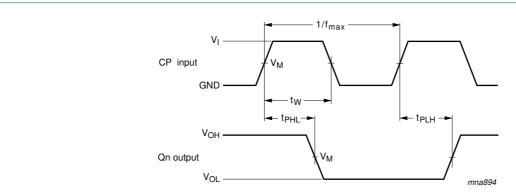
^[4] t_{en} is the same as t_{PZH} and t_{PZL} .

^[5] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

^[6] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

Octal D-type flip-flop; positive edge-trigger; 3-state

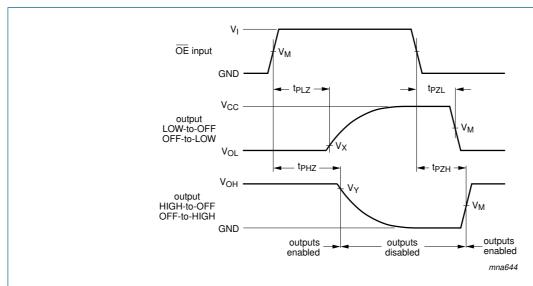
11. Waveforms



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 7. The clock (CP) to output (Qn) propagation delays, the clock pulse (CP) and the maximum clock pulse frequency



Measurement points are given in Table 8.

 $\ensuremath{V_{OL}}$ and $\ensuremath{V_{OH}}$ are typical output voltage levels that occur with the output load.

Fig 8. Enable and disable times

Octal D-type flip-flop; positive edge-trigger; 3-state

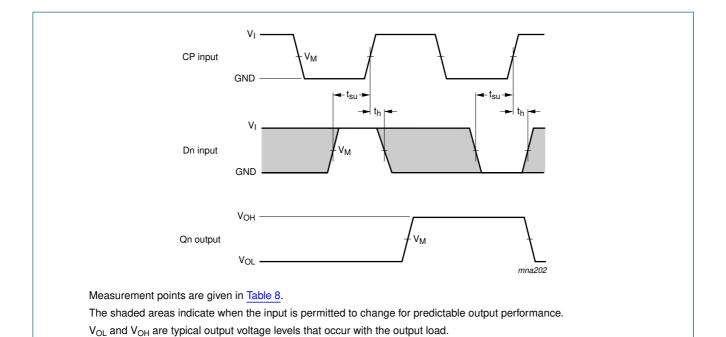
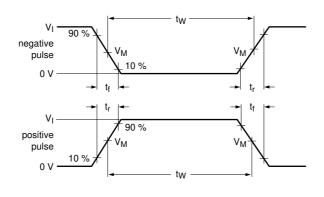


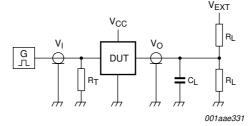
Fig 9. The data set-up and hold times for the Dn input to the CP input)

Table 8. Measurement points

Supply voltage	Input	Output	ıtput							
V _{CC}	V _M	V _M	V _x	V _y						
< 2.7 V	0.5V _{CC}	0.5V _{CC}	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$						
2.7 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V						
≥ 4.5 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V						

Octal D-type flip-flop; positive edge-trigger; 3-state





Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 10. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V _{EXT}			
V _{CC}	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t_{PZL} , t_{PLZ}	
< 2.7 V	V _{CC}	≤ 2.5 ns	50 pF	1 kΩ	open	GND	2V _{CC}	
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	15 pF, 50 pF	1 kΩ	open	GND	2V _{CC}	
≥ 4.5 V	V _{CC}	≤ 2.5 ns	50 pF	1 kΩ	open	GND	2V _{CC}	

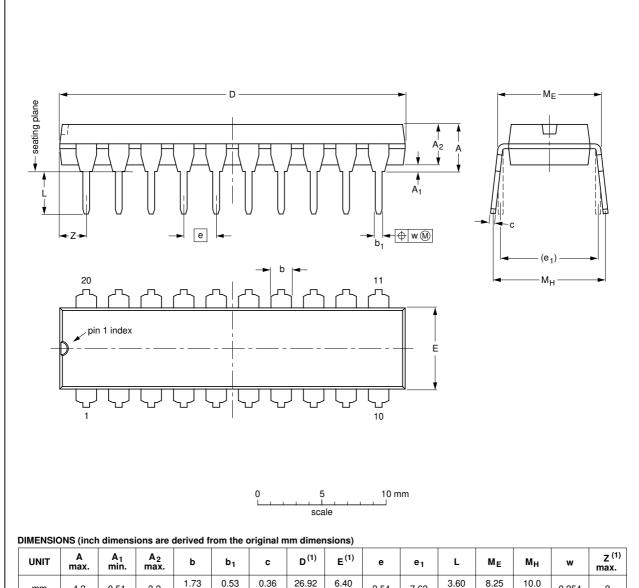
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Octal D-type flip-flop; positive edge-trigger; 3-state

12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



	•					•									
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

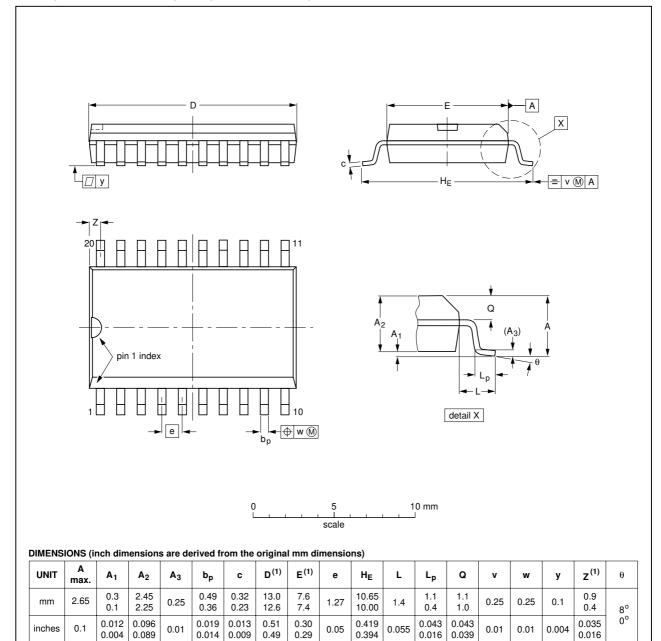
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTIO		ISSUE DATE
SOT146-1		MS-001	SC-603			99-12-27 03-02-13
					<u>'</u>	

Fig 11. Package outline SOT146-1 (DIP20)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	155UE DATE	
SOT163-1	075E04	MS-013				-99-12-27 03-02-19	

Fig 12. Package outline SOT163-1 (SO20)

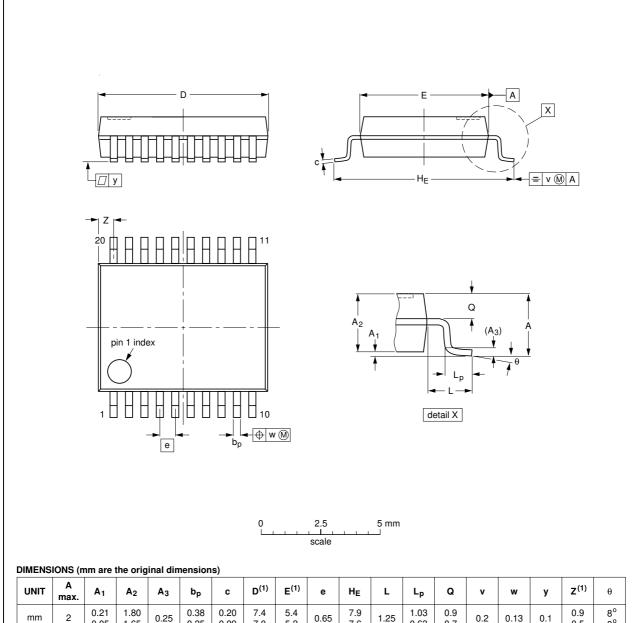
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74LV574 **NXP Semiconductors**

Octal D-type flip-flop; positive edge-trigger; 3-state

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC JEDE		JEITA	PROJECTION	ISSUE DATE	
SOT339-1		MO-150			99-12-27 03-02-19	

Fig 13. Package outline SOT339-1 (SSOP20)

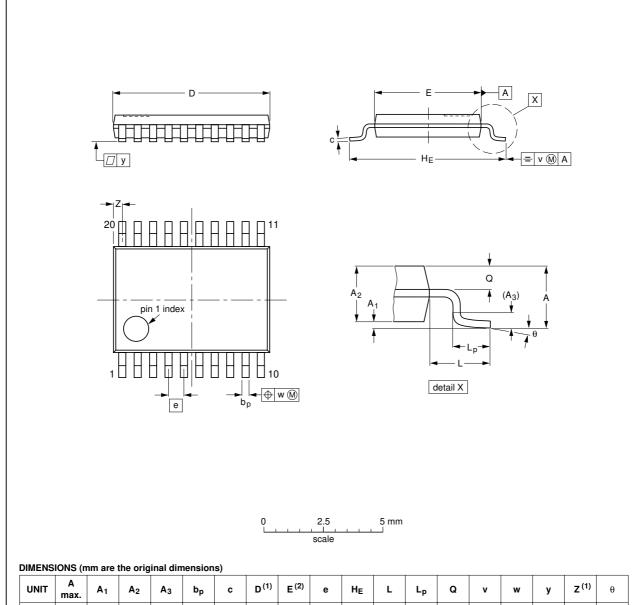
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74LV574 **NXP Semiconductors**

Octal D-type flip-flop; positive edge-trigger; 3-state

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



						-,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

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Fig 14. Package outline SOT360-1 (TSSOP20)

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Octal D-type flip-flop; positive edge-trigger; 3-state

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV574_4	20090514	Product data sheet	-	74LV574_3
Modifications:	 Typo remove 	ed from Figure 8 and Table 8	adapted accordingly	
74LV574_3	20090416	Product data sheet	-	74LV574_2
74LV574_2	19970203	Product specification	-	74LV574_1
74LV574_1	19980610	Product specification	-	-

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15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Octal D-type flip-flop; positive edge-trigger; 3-state

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